

PC817 Series

勝特力材料 886-3-5753170
 勝特力电子(上海) 86-21-34970699
 勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

High Density Mounting Type Photocoupler

- ✱ Lead forming type (I type) and taping reel type (P type) are also available. (PC817I/PC817P)
- ✱ TÜV (VDE0884) approved type is also available as an option.

■ Features

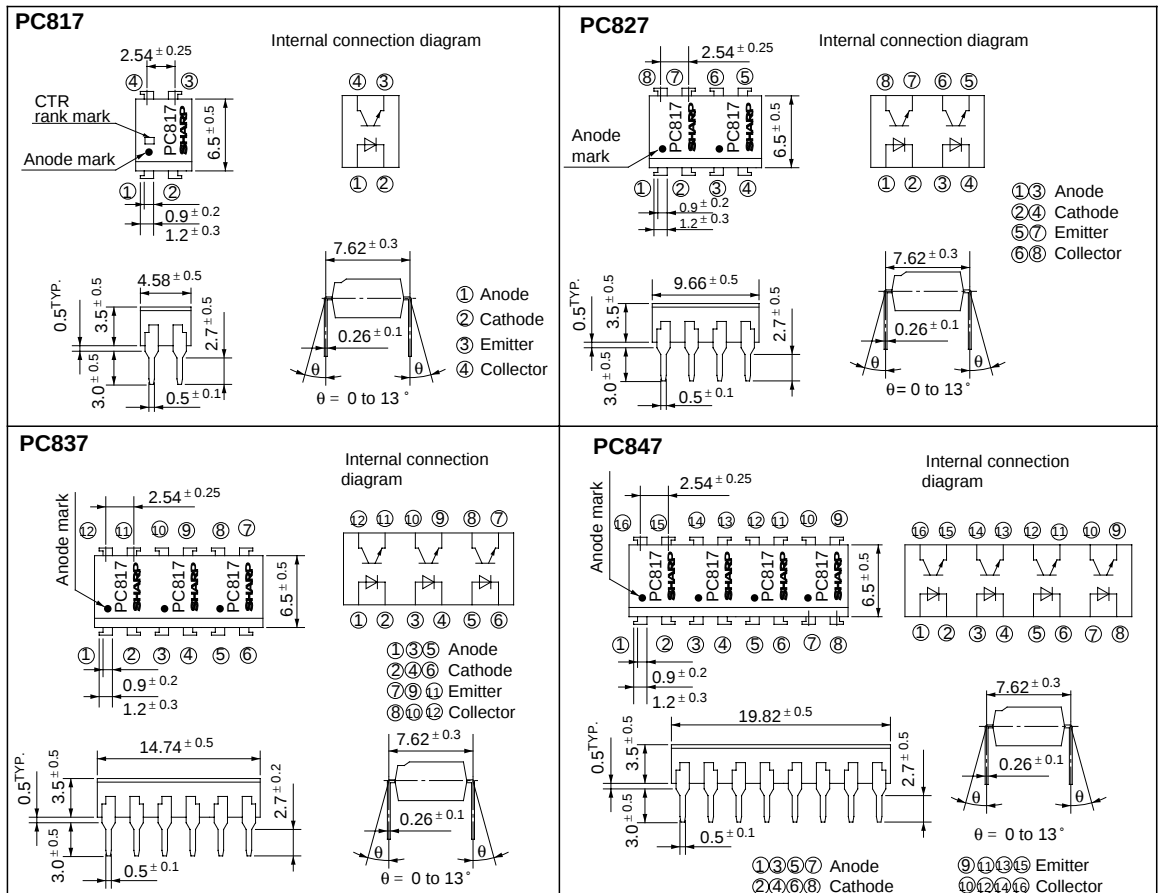
- Current transfer ratio
(CTR: MIN. 50% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)
- High isolation voltage between input and output (V_{iso} : 5 000V_{rms})
- Compact dual-in-line package
PC817: 1-channel type
PC827: 2-channel type
PC837: 3-channel type
PC847: 4-channel type
- Recognized by UL, file No. E64380

■ Applications

- Computer terminals
- System appliances, measuring instruments
- Registers, copiers, automatic vending machines
- Electric home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

(Unit: mm)



■ Absolute Maximum Ratings

(Ta = 25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	*1 Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _C	50	mA
	Collector power dissipation	P _C	150	mW
	Total power dissipation	P _{tot}	200	mW
	*2 Isolation voltage	V _{iso}	5 000	V _{rms}
	Operating temperature	T _{opr}	- 30 to + 100	°C
	Storage temperature	T _{stg}	- 55 to + 125	°C
	*3 Soldering temperature	T _{sol}	260	°C

*1 Pulse width ≤ 100μs, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics

(Ta = 25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 20mA	-	1.2	1.4	V
	Peak forward voltage	V _{FM}	I _{FM} = 0.5A	-	-	3.0	V
	Reverse current	I _R	V _R = 4V	-	-	10	μA
	Terminal capacitance	C _t	V = 0, f = 1kHz	-	30	250	pF
Output	Collector dark current	I _{CEO}	V _{CE} = 20V	-	-	10 ⁻⁷	A
Transfer characteristics	*4 Current transfer ratio	CTR	I _F = 5mA, V _{CE} = 5V	50	-	600	%
	Collector-emitter saturation voltage	V _{CE(sat)}	I _F = 20mA, I _C = 1mA	-	0.1	0.2	V
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 × 10 ¹⁰	10 ¹¹	-	Ω
	Floating capacitance	C _f	V = 0, f = 1MHz	-	0.6	1.0	pF
	Cut-off frequency	f _c	V _{CE} = 5V, I _C = 2mA, R _L = 100 Ω, - 3dB	-	80	-	kHz
Response time	Rise time	t _r	V _{CE} = 2V, I _C = 2mA, R _L = 100 Ω	-	4	18	μs
	Fall time	t _f		-	3	18	μs

*4 Classification table of current transfer ratio is shown below.

Model No.	Rank mark	CTR (%)
PC817A	A	80 to 160
PC817B	B	130 to 260
PC817C	C	200 to 400
PC817D	D	300 to 600
PC8※7AB	A or B	80 to 260
PC8※7BC	B or C	130 to 400
PC8※7CD	C or D	200 to 600
PC8※7AC	A, B or C	80 to 400
PC8※7BD	B, C or D	130 to 600
PC8※7AD	A, B, C or D	80 to 600
PC8※7	A, B, C, D or No mark	50 to 600

※ : 1 or 2 or 3 or 4

Fig. 1 Forward Current vs. Ambient Temperature

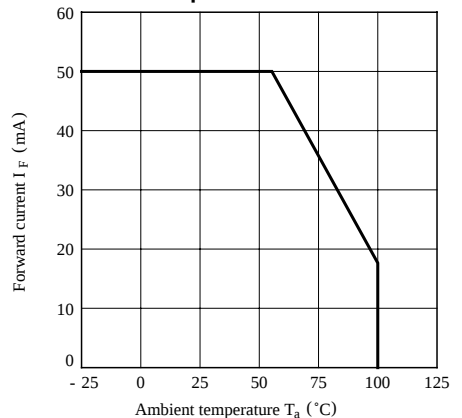


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

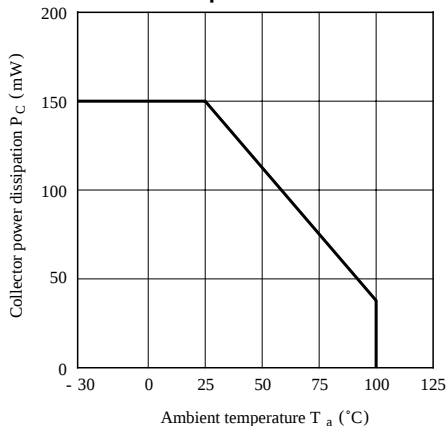


Fig. 3 Peak Forward Current vs. Duty Ratio

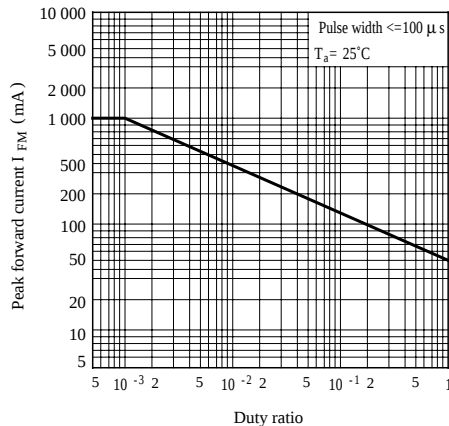


Fig. 4 Current Transfer Ratio vs. Forward Current

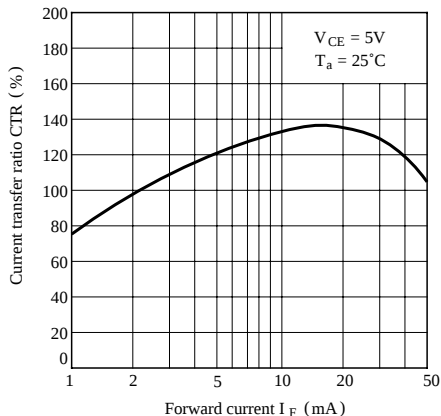


Fig. 5 Forward Current vs. Forward Voltage

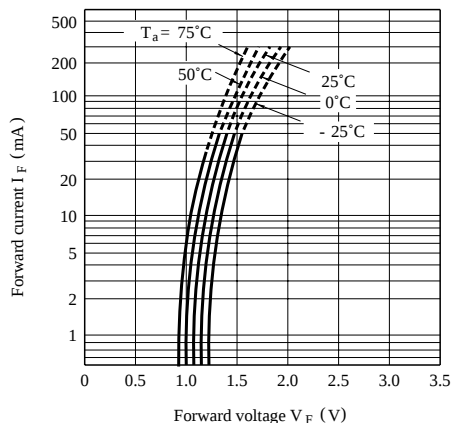


Fig. 6 Collector Current vs. Collector-emitter Voltage

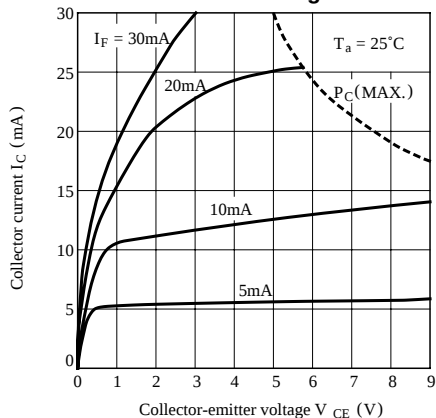


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

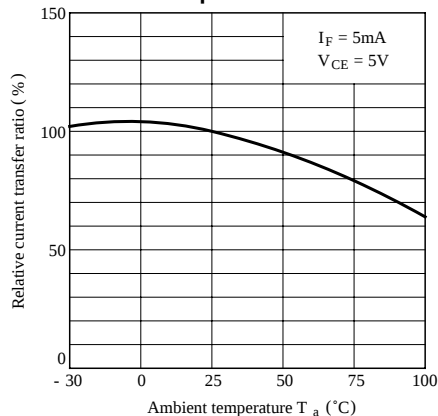


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

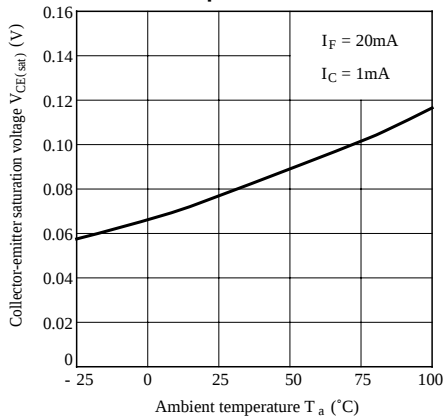


Fig. 9 Collector Dark Current vs. Ambient Temperature

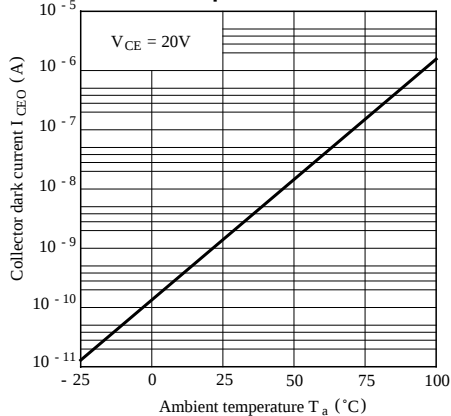


Fig.10 Response Time vs. Load Resistance

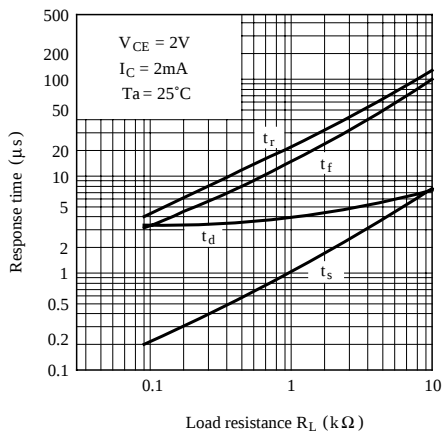
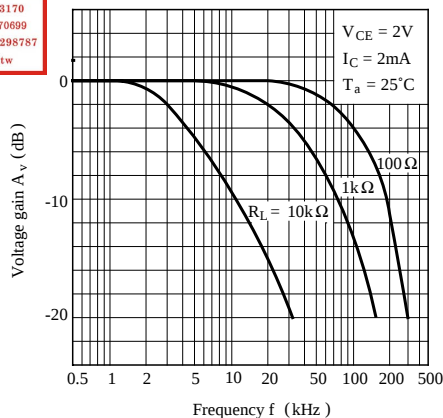
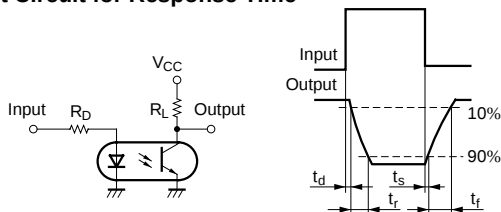


Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response

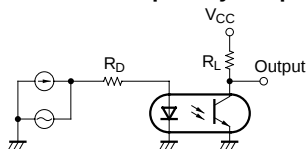


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current

